Matrix Optimization on Universal Unitary Photonic Devices

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(Received 7 August 2018; revised manuscript received 18 April 2019; published 19 June 2019)

Universal unitary photonic devices can apply arbitrary unitary transformations to a vector of input modes and provide a promising hardware platform for fast and energy-efficient machine learning using light. We simulate the gradient-based optimization of random unitary matrices on universal photonic devices composed of imperfect tunable interferometers. If device components are initialized uniformly randomly, the locally interacting nature of the mesh components biases the optimization search space toward banded unitary matrices, limiting convergence to random unitary matrices. We detail a procedure for initializing the device by sampling from the distribution of random unitary matrices and show that this greatly improves convergence speed. We also explore mesh architecture improvements such as adding extra tunable beam splitters or permuting waveguide layers to further improve the training speed and scalability of these devices.

DOI: 10.1103/PhysRevApplied.11.064044

I. INTRODUCTION

Universal multiport interferometers are optical networks that perform arbitrary unitary transformations on input vectors of coherent light modes. Such devices can be used in applications including quantum computing (e.g., boson sampling, photon walks) [1–4]; mode unscramblers [5]; photonic neural networks [6–8]; and finding optimal channels through lossy scatterers [9]. While universal photonic devices have been experimentally realized at a relatively small scale [5,6], commercial applications such as hardware for energy-efficient machine learning and signal processing can benefit from scaling the devices to up to $N = 1000$ modes. At this scale, fabrication imperfections and components with scale-dependent sensitivities can negatively affect performance.

One canonical universal photonic device is the rectangular multiport interferometer mesh [10] shown in Fig. 1 interfering $N = 8$ modes. In multiport interferometers, an $N$-dimensional vector is represented by an array of modes arranged in $N$ single-mode waveguides. A unitary operation is applied to the input vector by tuning Mach-Zehnder interferometers (MZIs) represented by the red dots of Fig. 1. Each MZI is a two-port optical component made of two 50:50 beam splitters and two tunable single-mode phase shifters. Other mesh architectures have been proposed, such as the triangular mesh [11] (shown in Appendix C), the universal cascaded binary tree architecture [12], and lattice architectures where light does not move in a forward-only direction [13–15].

The scalability of optimizing mesh architectures, especially using gradient-based methods, is limited by the ability of the locally interacting architecture to control the output powers in the mesh. If phase shifts in the mesh are initialized uniformly randomly, light propagates through the device in a manner similar to a random walk. The off-diagonal, nonlocal elements of the implemented unitary matrix tend to be close to zero because transitions between inputs and outputs that are far apart have fewer paths (e.g., input 1 and output 8 in Fig. 1 have a single path). The resulting mesh therefore implements a unitary matrix with a banded structure that is increasingly pronounced as the matrix size increases.

In many applications such as machine learning [6] and quantum computing [2,16], we avoid this banded unitary matrix behavior in favor of random unitary matrices. A random unitary matrix is achieved when the device phase shifts follow a distribution derived from random matrix theory [16–20]. In the random matrix theory model, we assign a sensitivity index to each component that increases toward the center of the mesh, as shown in Fig. 1. The more sensitive components toward the center of the mesh require higher transmissivities and tighter optimization tolerances. If the required tolerances are not met, the implemented unitary matrix begins to show the undesired banded behavior.

In Sec. II, we introduce the photonic mesh architecture and sources of error that can exacerbate the banded unitary matrix problem. In Sec. III, we explicitly model the
A. Photonic unitary implementation

A single-mode phase shifter can perform an arbitrary $U(1)$ transformation $e^{i\theta}$ on its input. A phase-modulated MZI with perfect (50:50) beam splitters can apply to its inputs a unitary transformation $U$ of the form

$$U(\theta, \phi) := R_\phi B R_\theta B$$

$$= \frac{1}{2} \begin{bmatrix} e^{i\phi} & 0 \\ 0 & 1 \end{bmatrix} \begin{bmatrix} 1 & i \\ i & 1 \end{bmatrix} \begin{bmatrix} e^{i\theta} & 0 \\ 0 & 1 \end{bmatrix} \begin{bmatrix} 1 & i \\ i & 1 \end{bmatrix}$$

$$= ie^{i\phi/2} \begin{bmatrix} e^{i\theta} \cos \frac{\theta}{2} & e^{i\theta} \sin \frac{\theta}{2} \\ \cos \frac{\theta}{2} & -\sin \frac{\theta}{2} \end{bmatrix},$$

where $B$ is the beam-splitter operator and $R_\theta, R_\phi$ are upper phase-shift operators. Equation (1) is represented diagrammatically by the configuration in Fig. 1. (Other configurations with two independent phase shifters between the beam splitters $B$ are ultimately equivalent for photonic meshes [21].) If one or two single-mode phase shifters are added at the inputs, we can apply an arbitrary SU(2) or $U(2)$ transformation to the inputs, respectively.

We define the transmissivity and reflectivity of the MZI as

$$t := \cos^2 \left( \frac{\theta}{2} \right) = |U_{12}|^2 = |U_{21}|^2,$$

$$r := \sin^2 \left( \frac{\theta}{2} \right) = 1 - t = |U_{11}|^2 = |U_{22}|^2.$$  

In this convention, when $\theta = \pi$, we have $r = 1, t = 0$ (the MZI “bar state”), and when $\theta = 0$, we have $r = 0, t = 1$ (the MZI “cross state”).

If there are $N$ input modes and the interferometer is connected to waveguides $n$ and $n + 1$, then we can embed the $2 \times 2$ unitary $U$ from Eq. (1) in $N$-dimensional space with a locally interacting unitary “Givens rotation” $U_n$ defined as

$$U_n := \begin{bmatrix} 1 & \cdots & 0 & \cdots & 0 \\ \vdots & \ddots & \vdots & \ddots & \vdots \\ 0 & \cdots & U_{11} & U_{12} & \cdots \\ 0 & \cdots & U_{21} & U_{22} & \cdots \\ \vdots & \cdots & \vdots & \ddots & \vdots \\ 0 & \cdots & 0 & \cdots & 1 \end{bmatrix},$$

All diagonal elements are 1 except those labeled $U_{11}$ and $U_{22}$, which have magnitudes of $\sqrt{r} = \sqrt{T - t}$, and all off-diagonal elements are 0 except those labeled $U_{12}$ and $U_{21}$, which have magnitudes of $\sqrt{t}$.
Arbitrary unitary transformations can be implemented on a photonic chip using only locally interacting MZIs [11]. In this paper, we focus on optimizing a rectangular mesh [10] of MZIs; however, our ideas can be extended to other universal schemes, such as the triangular mesh [22], as well.

In the rectangular mesh scheme [10] of Fig. 1, we represent $\hat{U}_R \in U(N)$ in terms of $N(N-1)/2$ locally interacting Givens rotations $U_n$ and $N$ single-mode phase shifts at the inputs represented by diagonal unitary $D(\gamma_1, \gamma_2, \ldots, \gamma_N)$:

$$
\hat{U}_R := \prod_{\ell=1}^{N} \prod_{n \in S_{\ell,N}} U_n(\theta_n, \phi_n) \cdot D(\gamma_1, \gamma_2, \ldots, \gamma_N),
$$

where our layerwise product left-multiplies from $\ell = N$ to $1$ (in general, for matrix products for a sequence $\{M_i\}$, we define the multiplication order $\prod_{\ell=1}^N M_{\ell} = M_0^N M_{N-1} \cdots M_1$); the single-mode phase shifts are $\gamma_n \in [0, 2\pi]$; and the Givens rotations are parameterized by $\theta_n \in [0, \pi], \phi_n \in [0, 2\pi]$. (Since $\gamma_n, \phi_n$ are periodic phase parameters, they are in half-open intervals $[0, 2\pi)$. In contrast, any $\theta_n \in [0, \pi]$ must be in a closed interval to achieve all transmissivities $t_{\ell} \in [0, 1]$.) We define the top indices of each interacting mode for each vertical layer as the set $S_{\ell,N} = \{n \in \{1, 2, \ldots, N-1\} \; | \; n \mod 2 \equiv \ell \mod 2\}$. This vertical layer definition follows the convention of Refs. [23] and [7] and is depicted in Fig. 1, where $\ell$ represents the index of the vertical layer.

### B. Beam-splitter error tolerances

The expressions in Eqs. (1) and (4) assume perfect fabrication. In practice, however, we would like to simulate how practical devices with errors in each transfer matrix $B, R_\theta, R_\phi$ in Eq. (1) impact optimization performance.

In fabricated chip technologies, imperfect beam splitters $B$ can have a split ratio error $\epsilon$ that changes the behavior of the red 50:50 coupling regions in Fig. 1 or $B$ in Eq. (1). The resultantly scattering matrix $U_e$ with imperfect beam splitters $B_e$ can be written as

$$
B_e := \frac{1}{2} \begin{bmatrix} \sqrt{1+\epsilon} & i\sqrt{1-\epsilon} \\ i\sqrt{1-\epsilon} & \sqrt{1+\epsilon} \end{bmatrix},
$$

$$
U_e := R_\phi B_e R_\theta R_\phi B_e.
$$

As shown in Appendix B, if we assume both beam splitters have identical $\epsilon$, we find that $t_e := t(1-\epsilon^2) \in [0, 1-\epsilon^2]$ is the realistic transmissivity; $r_e := r + t \cdot \epsilon^2 \in [\epsilon^2, 1]$ is the realistic reflectivity; and $t, r$ are the ideal transmissivity and reflectivity defined in Eq. (2).

The unitary matrices in Eq. (5) cannot express the full transmissivity range of the MZI, with errors of up to $\epsilon^2$ in the transmissivity, potentially limiting the performance of greedy progressive photonic algorithms [24–26]. Our Haar phase theory, which we develop in the following section, determines acceptable interferometer tolerances for calibration of a “perfect mesh” consisting of imperfect beam splitters [21] given large $N$. We will additionally show that simulated photonic backpropagation [7] with adaptive learning can adjust to nearly match the performance of perfect meshes with errors as high as $\epsilon = 0.1$ for meshes of size $N = 128$.

### C. Phase-shift tolerances

Another source of uncertainty in photonic meshes is the phase-shift tolerances of the mesh that affect the matrices $R_\theta, R_\phi$ of Eq. (1), shown in orange in Fig. 1. Error sources such as thermal cross talk or environmental drift may result in slight deviance of phase shifts in the mesh from intended operation. Such errors primarily affect the control parameters $\theta_n$ that control light propagation in the mesh by affecting the MZI split ratios. This nontrivial problem warrants a discussion of mean behavior and sensitivities (i.e., the distribution) of $\theta_n$ needed to optimize a random unitary matrix.

### III. HAAR INITIALIZATION

#### A. Cross-state bias and sensitivity index

The convergence of global optimization depends critically on the sensitivity of each phase shift. The gradient descent optimization we study in this paper converges when the phase shifts are correct to within some acceptable range. This acceptable range can be rigorously defined in terms of average value and variance of phase shifts in the mesh that together define an unbiased (“Haar random”) unitary matrix. (A Haar random unitary is defined as Gram-Schmidt orthogonalization of $N$ standard normal complex vectors [16,20].) To implement a Haar random unitary, some MZIs in the mesh need to be biased toward a cross state ($t_{\ell} \approx 1$, $\theta_{\ell} \approx 0$) [16,24]. This cross-state bias correspondingly “pinches” the acceptable range for transmissivity and phase shift near the limiting cross-state configuration, resulting in higher sensitivity, as can be seen in Fig. 3(b).

For an implemented Haar random unitary matrix, low-tolerance, transmissive MZIs are located toward the center of a rectangular mesh [16,24] and the apex of a triangular mesh as proven in Appendix C. For both the triangular and rectangular meshes, the cross-state bias and corresponding sensitivity for each MZI depend only on the total number of reachable waveguide ports, as proven in Appendix I. Based on this proof, we define the sensitivity index $\alpha_{nt} := |I_{nt}| + |O_{nt}| - N - 1$ (note that $1 \leq \alpha_{nt} \leq N - 1$, and there are always $N - \alpha_{nt}$ MZIs that have a sensitivity index of $\alpha_{nt}$), where $I_{nt}$ and $O_{nt}$ are the subsets of input and output waveguides reachable by light exiting or entering the MZI, respectively, and $|\cdot|$ denotes set size.
FIG. 2. (a) The sensitivity index $\alpha_{nl}$ for $N = 64$. (b) Checkerboard plot for the average reflectivity $\langle r_{nl} \rangle$ in a rectangular mesh. (c) Decomposition of Ref. [10] for a Haar-random matrix yields phases close to cross state in the middle of the mesh. (d) The Haar phase $\xi_{nl}$ for the rectangular mesh better displays the randomness. (e),(f) Field measurements (absolute value) from propagation at input 32 in (e) Haar and (f) uniform random initialized rectangular meshes with $N = 64$.

Figures 1 and 2(a) show the sensitivity index for the rectangular mesh, which clearly increases toward the center MZI.

B. Phase-shift distributions and Haar phase

The external $\phi_{nl}$, $\gamma_{nl}$ phase shifts do not affect the transmissivity $t_{nl}$ and therefore obey uniform random distributions [16]. In contrast, the $\theta_{nl}$ phase shifts have a probability density function (PDF) that depends on $\alpha_{nl}$ [16]:

$$P_{\alpha_{nl}}\left(\frac{\theta_{nl}}{2}\right) = \alpha_{nl} \sin \left(\frac{\theta_{nl}}{2}\right) \left[ \cos \left(\frac{\theta_{nl}}{2}\right) \right]^{2\alpha_{nl}-1}. \quad (6)$$

The general shape of this distribution is presented in Fig. 3(b), showing how an increase in $\alpha_{nl}$ biases $\theta_{nl}$ toward the cross state with higher sensitivity.

We define the Haar phase $\xi_{nl}$ as the cumulative distribution function (CDF) of $\theta_{nl}/2$ starting from $\theta_{nl}/2 = \pi/2$:

$$\xi_{nl} := \int_{\pi/2}^{\theta_{nl}/2} P_{\alpha_{nl}}(\theta) d\theta. \quad (7)$$

Using Eqs. (6) and (7), we can define $\xi_{nl}(\theta_{nl}) \in [0, 1]$ that yields a Haar random matrix:

$$\xi_{nl} = \left[ \cos^2 \left(\frac{\theta_{nl}}{2}\right) \right]^{\alpha_{nl}} = t_{nl}^{\alpha_{nl}}, \quad (8)$$

where $t_{nl}$ represents the transmissivity of the MZI, which is a function of $\theta_{nl}$ as defined in Eqs. (2).

C. Haar initialization

In the physical setting, it is useful to find the inverse of Eq. (8) to directly set the measurable transmissivity $t_{nl}$ of each MZI using a uniformly varying Haar phase $\xi_{nl} \sim U(0, 1)$, a process we call “Haar initialization,” shown in Figs. 2(c) and 2(d):

$$t_{nl} = \alpha_{nl} \sqrt{\xi_{nl}},$$

$$\theta_{nl} = 2 \arccos \sqrt{t_{nl}} = 2 \arccos \frac{2\alpha_{nl}}{\sqrt{\xi_{nl}}}, \quad (9)$$

where the expression for $\theta_{nl}$ is just a rearrangement of Eq. (2).
Haar initialization can be achieved progressively using a procedure similar to that in Ref. [25]. If the phase shifters in the mesh are all well characterized, the transmissivities can be directly set [16]. We show in Sec. V that Haar initialization improves the convergence speed of gradient descent optimization significantly.

We can also use Eq. (9) to find the average transmissivity and reflectivity for a MZI parameterized by \( \alpha_{nl} \) as is found through simulation in Ref. [24]:

\[
\langle t_{nt} \rangle = \int_0^1 d\xi_{nt} \frac{a_n}{\sqrt{\xi_{nt}}} = \frac{\alpha_{nt}}{\alpha_{nt} + 1},
\]

\[
\langle r_{nt} \rangle = \frac{1}{\alpha_{nt} + 1} = \frac{1}{|I_{nt}| + |O_{nt}| - N}.
\]

The average reflectivity \( \langle r_{nt} \rangle \) shown in Fig. 2(b) gives a simple interpretation for the sensitivity index shown in Fig. 2(a). The average reflectivity is equal to the inverse of the total number of inputs and outputs reachable by the MZI minus the number of ports on either side of the device, \( N \). This is true regardless of whether \( \alpha_{nt} \) is assigned for a triangular or rectangular mesh.

To see what the Haar initialization has accomplished, we can compare the field propagation through the rectangular mesh from a single input when it is Haar initialized versus uniform initialized in Fig. 2(e). Physically, this corresponds to light in the mesh spreading out quickly from the input of the mesh and “interacting” more near the boundaries of the mesh (inputs, outputs, top, and bottom), as compared to the center of the mesh, which has high transmissivity. In contrast, when phases are randomly set, the light effectively follows a random walk through the mesh, resulting in the field propagation pattern shown in Fig. 2(f).

D. Tolerance dependence on \( N \)

While Haar initialization is based on how the average component reflectivity scales with \( N \), optimization convergence and device robustness ultimately depend on how phase-shift tolerances scale with \( N \). The average sensitivity index in the mesh is \( \langle \sigma_{nt} \rangle = (N + 1)/3 \). As shown in Figs. 3(b) and 3(c), the standard deviation \( \sigma_{\theta,\alpha} \) over the PDF \( P_\alpha \) decreases as \( \alpha \) increases. Therefore, a phase shifter’s allowable tolerance, which roughly correlates with \( \sigma_{\theta,\alpha} \), decreases as the total number of input and output ports affected by that component increases. Since \( \langle \alpha_{nt} \rangle \) increases linearly with \( N \), the required tolerance gets more restrictive at large \( N \), as shown in Fig. 3(c). We find that the standard deviation is on the order \( 10^{-2} \) radians for most values of \( N \) in the specified range. Thus, if thermal cross talk is ignored [6], it is possible to implement a known random unitary matrix in a photonic mesh assuming perfect operation. However, we concern ourselves with on-chip optimization given just input and output data, in which case the unitary matrix is unknown. In such a case, the decreasing tolerances do pose a challenge in converging to a global optimum as \( N \) increases. We demonstrate this problem for \( N = 128 \) in Sec. V.

To account for the scalability problem in global optimization, one strategy may be to design a component in such a way that the mesh MZIs can be controlled by Haar phase voltages as in Fig. 3(d) and Eq. (9). The transmissivity dependence on a periodic Haar phase [shown in Fig. 3(d) and discussed in Appendix G] is markedly different from the usual sinusoidal dependence on periodic \( \theta_{nt} \). The MZIs near the boundary vary in transmissivity over a larger voltage region than the MZIs near the center, where only small voltages are needed get to full transmissivity. This results in an effectively small control tolerance near small voltages. This motivates the modifications to the mesh architecture which we discuss in the next section.

IV. ARCHITECTURE MODIFICATIONS

We propose two architecture modifications that can relax the transmissivity tolerances in the mesh discussed in Sec. III and result in significant improvement in optimization.

A. Redundant rectangular mesh

By adding extra tunable MZIs, it is possible to greatly accelerate the optimization of a rectangular mesh to an unknown unitary matrix. The addition of redundant tunable layers to a redundant rectangular mesh (RRM) is depicted in green in Fig. 4(a). The authors in Ref. [24] point out that using such “underdetermined meshes” (number of inputs less than the number of tunable layers in the mesh) can overcome photonic errors and restore fidelity in unitary construction algorithms. Adding layers to the mesh increases the overall optical depth of the device, but embedding smaller meshes with extra beam-splitter layers in a rectangular mesh of an acceptable optical depth does not pose intrinsic waveguide loss-related problems.

B. Permuting rectangular mesh

Another method to accelerate the optimization of a rectangular mesh is to shuffle outputs at regular intervals within the rectangular mesh. This shuffling relaxes component tolerances and uniformity of the number of paths for each input-output transition. We use this intuition to formally define a permuting rectangular mesh (PRM). For simplicity, assume \( N = 2^K \) for some positive integer \( K \). Define “rectangular permutation” operations \( P_K \) that allow inputs to interact with waveguides at most \( 2^k \) away for \( k < K \). These rectangular permutation blocks can be implemented using a rectangular mesh composed of MZIs with fixed cross-state phase shifts, as shown in Fig. 4(b), or using low-loss waveguide crossings.
FIG. 4. (a) A 16 × 16 rectangular mesh (red). Extra tunable layers (green) may be added to significantly reduce convergence time. (b) A 16-input, 30-layer permuting rectangular mesh. The rectangular permutation layer is implemented using either waveguide crossings or cross-state MZIs (gray).

We now add permutation matrices $P_1, P_2, \ldots, P_{K-1}$ into the middle of the rectangular mesh as follows:

$$
\hat{U}_{PR} := M_K \left( \prod_{k=1}^{K-1} P_k M_k \right),
$$

where $\min \left( k \left\lceil \frac{N}{K} \right\rceil, N \right)$

$$
M_k := \prod_{\ell=(k-1)\left\lceil \frac{N}{K} \right\rceil}^{\ell\left\lceil \frac{N}{K} \right\rceil} \prod_{n \in S_{\ell,N}} U_\ell(\theta_n, \phi_n),
$$

with $\lceil x \rceil$ representing the nearest integer larger than $x$.

There are two operations per block $k$: an $\lceil N/K \rceil$-layer rectangular mesh, which we abbreviate as $M_k$, and the rectangular permutation mesh $P_k$, where block index $k \in [1 \cdots K - 1]$. This is labeled in Fig. 4(b).

V. SIMULATIONS

Now that we have discussed the mesh modifications and Haar initialization, we simulate global optimization to show how our framework can improve convergence performance by up to five orders of magnitude, even in the presence of fabrication error.

A. Mesh initialization

We begin by discussing the importance of initializing the mesh to respect the cross-state bias and sensitivity of each component for the Haar random unitary matrices discussed in Sec. III. Uniform random phase initialization is problematic because it is agnostic of the sensitivity and average behavior of each component. We define this distribution of matrices as $U_R(N, L)$ for a rectangular mesh for $N$ inputs and $L$ layers. As shown previously in Fig. 2(f), any given input follows a random-walklike propagation if phases are initialized uniform randomly, so there will only be nonzero matrix elements within a "bandsize" about the diagonal. This bandsize decreases as circuit size $N$ increases as shown in Fig. 5.

We compare the bandsizes of banded unitary matrices in simulations qualitatively as we do in Fig. 5 or quantitatively as we do in Appendix D. We randomly generate $U \sim U_R(N, N)$, $U \sim U_{PR}(N)$ (permuting rectangular mesh with $N$ tunable layers), and $U \sim U_{PR}(N, N + \delta N)$ (redundant rectangular mesh with $\delta N$ extra tunable layers). Figure 5 shows a significant reduction in bandsize as $N$ grows larger for rectangular meshes. This phenomenon is not observed with permuting rectangular meshes, which generally have the same bandsize as Haar random matrices (independent of $N$) as shown in Fig. 5 and Appendix D. This correlates with permuting rectangular meshes having faster optimization and less dependence on initialization.

Instead of initializing the mesh using uniform random phases, we use Haar initialization as in Eq. (9) to avoid starting with a banded unitary configuration. This initialization, which we recommend for any photonic mesh-based neural network application, dramatically improves convergence because it primes the optimization with the right average behavior for each component. We find in our simulations that as long as the initialization is calibrated...
toward higher transmissivity ($\theta_{nl}$ near 0), larger mesh networks can also have reasonable convergence times similar to when the phases are Haar initialized.

The proper initialization of permuting rectangular meshes is less clear because the tolerances and average behavior of each component have not yet been modeled. Our proposal is to initialize each tunable block $M_k$ as an independent mesh using the same definition for $\alpha_{nl}$, except replacing $N$ with the number of layers in $M_k$, $\lceil N/K \rceil$. This is what we use as the Haar initialization equivalent in the permuting rectangular mesh case, although it is possible there may be better initialization strategies for the nonlocal mesh structure.

### B. Optimization problem and synthetic data

After initializing the photonic mesh, we proceed to optimize the mean-square error cost function for an unknown Haar random unitary $U$:

$$\min_{\theta_{nl}, \phi_{nl}, \gamma_n} \frac{1}{2N} \left\| \hat{U}(\theta_{nl}, \phi_{nl}, \gamma_n) - U \right\|_F^2,$$

where $\hat{U}(\theta_{nl}, \phi_{nl}, \gamma_n)$ maps $N^2$ phase-shift parameters $\theta_{nl}, \phi_{nl}, \gamma_n$ to $U(N)$ via Eq. (4) or (11) and $\| \cdot \|_F$ denotes the Frobenius norm. Since trigonometric functions parameterizing $\hat{U}$ are nonconvex, we know that Eq. (12) is a nonconvex problem. The nonconvexity of Eq. (12) suggests learning a single unitary transformation in a deep neural network might have significant dependence on initialization.

To train the network, we generate random unit-norm complex input vectors of size $N$ and generate corresponding labels by multiplying them by the target matrix $U$. We use a training batch size of $2N$. The synthetic training data of unit-norm complex vectors is therefore represented by $X \in \mathbb{C}^{N \times 2N}$. The minibatch training cost function is similar to the test cost function, $L_{\text{train}} = \| \hat{U}X - UX \|_F^2$. The test set is the identity matrix $I$ of size $N \times N$. The test cost function, in accordance with the training cost function definition, thus matches Eq. (12).

### C. Training algorithm

We simulate the global optimization of a unitary mesh using automatic differentiation in tensorflow, which can be physically realized using the in situ backpropagation procedure in Ref. [7]. This optical backpropagation procedure physically measures $\partial L_{\text{train}}/\partial \theta_{nl}$ using interferometric techniques, which can be extended to any of the architectures that we discuss in this paper.

The on-chip backpropagation approach is also likely faster for gradient computation than other training approaches such as the finite-difference method mentioned in past on-chip training proposals [6]. We find empirically that the Adam update rule (a popular first-order adaptive update rule [27]) outperforms the standard stochastic gradient descent for the training of unitary networks. If gradient measurements for the phase shifts are stored during training, adaptive update rules can be applied using successive gradient measurements for each tunable component in the mesh. Such a procedure requires minimal computation (i.e., locally storing the previous gradient step) and can act as a physical test of the simulations we now discuss. Furthermore, we avoid quasi-Newton optimization methods such as L-BFGS used in Ref. [24] that cannot be implemented physically as straightforwardly as first-order methods.

The models are trained using our open source simulation framework neuropilx (see Ref. [28]) using a more general version of the vertical layer definition proposed in Refs. [23] and [7]. The models are programmed in tensorflow [29] and run on an NVIDIA GeForce GTX1080 GPU to improve optimization performance.

### D. Results

We now compare training results for rectangular, redundant rectangular, and permuting rectangular meshes given $N = 128$. In our comparison of permuting rectangular meshes and rectangular meshes, we analyze performance when beam-splitter errors are distributed throughout the mesh as either $\epsilon = 0$ or $\epsilon \sim \mathcal{N}(0, 0.01)$ and when the $\theta_{nl}$ are randomly or Haar initialized [according to the PDF in Eq. (6)]. We also analyze optimization performances of redundant rectangular meshes where we vary the number of vertical MZI layers.

From our results, we report five key findings:

1. Optimization of $N = 128$ rectangular meshes results in significant off-diagonal errors due to bias toward the banded matrix space of $\hat{U}_R(128)$, as shown in Fig. 6.
2. Rectangular meshes converge faster when Haar initialized than when uniformly random initialized, as in Fig. 6, in which case the estimated matrix converges toward a banded configuration, as shown in Appendix H.
3. Permuting rectangular meshes converge faster than rectangular meshes despite having the same number of total parameters, as shown in Fig. 6.
4. Redundant rectangular meshes, because of an increase in the number of parameters, have up to 5 orders of magnitude better convergence when the number of vertical layers is doubled compared to rectangular and permuting rectangular meshes, as shown in Fig. 7.
5. Beam-splitter imperfections slightly reduce the overall optimization performance of permuting and redundant rectangular meshes, but reduce the performance of the rectangular mesh significantly. (See Fig. 6(a) and Appendix E.)
FIG. 6. We implement six different optimizations for $N = 128$, where we vary the choice of permuting rectangular mesh (PRM) or rectangular mesh (RM); the initialization (random $\theta_{\text{int}}$ or Haar-initialized $\theta_{\text{int}}$); and photonic transmissivity error displacements $[\epsilon = 0$ or $\epsilon \sim N(0,0.01)$, where $\sigma^2_\epsilon = 0.01$ is the variance of the beam-splitter errors]. The conditions are 20,000 iterations, Adam update, learning rate of 0.0025, batch size of 256, simulated in tensorflow. (a) Comparison of optimization performance (defaults are Haar initialization and $\epsilon_n^{\ell} = 0$ unless otherwise indicated). The optimized error magnitude spatial map for (b) rectangular mesh shows higher off-diagonal errors than (c) permuting rectangular. The optimized $\theta_{\text{int}}$ phase shifts (see Appendix G) for (d) rectangular meshes are close to zero (cross state) near the center as opposed to (e) permuting rectangular meshes, which have a striped pattern (likely due to initialization). Note that, by $|\cdot|$, we refer to the elementwise norm.

The singular value decomposition (SVD) architecture discussed in Refs. [22] and [6] consists of optical lossy components flanked on both sides by rectangular meshes and are capable of implementing any linear operation with reasonable device input power. Note that with some modifications (e.g., treating loss and gain elements like nonlinearities in the procedure of Ref. [7]), SVD architectures can also be trained physically using in situ backpropagation. We simulate the gradient-based optimization of SVD architectures using automatic differentiation in Appendix F.

VI. DISCUSSION

A. Haar initialization

For global optimization and robustness of universal photonic meshes, it is important to consider the required biases and sensitivities for each mesh component. Implementing any Haar random matrix requires that each component independently follow an average reflectivity within some tolerance. This requirement becomes more restrictive with the number of input and output ports accessible by each mesh component. For the rectangular mesh, this means the center mesh components are close to a cross state and the most sensitive.

In a Haar-initialized mesh, as shown in Fig. 2, the light injected into a single input port spreads out to all waveguides in the device uniformly regardless of $N$. This is a preferable initialization for global optimization because Haar random matrices require this behavior. In contrast, when randomly initializing phases, the light only spreads out over a limited band of outputs. This band gets relatively small when the mesh gets larger, as shown in Fig. 9.

The average reflectivities given by Haar initialization may be useful for inverse design approaches [30] for compact tunable or passive multiport interferometers. The component tolerances may inform how robust phase shifters need to be given error sources such as thermal...
cross talk [6]. The thermal cross talk might make it difficult to achieve required tolerances for devices interfering up to \( N = 1000 \) modes that generally have phase-shift tolerances just above \( 10^{-2} \) radians. [The authors of Ref. [6] propose that a standard deviation of approximately \( 10^{-3} \) might be possible with further circuit characterization, which might be scalable based on Fig. 3(c).]

In our simulations in Sec. V, we assume that the control parameter for photonic meshes is linearly related to the phase shift. However, in many current phase-shifter implementations, such as thermal phase shifters [6], the phase is a nonlinear function of the control parameter (i.e., the voltage) and has minimum and maximum values, unlike the unbounded phase used in our optimization. In addition, like the Haar phase in our theory, the voltage acts as the CDF for transmissivities in the physical device, up to a normalization factor. Particular attention needs to be given to phase uncertainty as a function of voltage, since the Haar random distribution of internal MZI phases has small variance for large \( N \), as we show in Fig. 3(c). As mentioned in Sec. III, the ideal transmissivity-voltage dependence with this consideration would be identical to the transmissivity vs Haar phase dependence in Fig. 3(d).

### B. Applications of mesh optimization

Meshes can be tuned using either self-configuration [11, 22] or global optimizations (gradient based [7] or derivative free [31]). The algorithmic optimizations proposed in Refs. [11,22] assume that each component in the mesh can cover the entire split ratio range, which is not the case in the presence of 50:50 beam-splitter errors. This ultimately leads to lower fidelity in the implemented unitary operation, which can be avoided using a double-MZI architecture [21,32] or a vertical layerwise progressive algorithm [25]. We explore a third alternative to overcome photon errors; gradient-based global optimization is model free and, unlike algorithmic approaches, can efficiently tune photonic neural networks [7]. This model-free property makes gradient-based optimization robust to fabrication error; we show in Fig. 6(a) that meshes with split ratio error variances of up to \( \sigma_e = 0.1 \) can be optimized nearly as well as a perfect mesh, particularly for permuting rectangular meshes.

In the regime of globally optimized meshes, we propose two strategies to modify the rectangular architecture: adding waveguide permutation layers and adding extra tunable vertical MZI layers. Both approaches relax the cross-state requirements on the MZIs and accelerate the mesh optimization process. Nonlocal interference works by allowing inputs that are far away physically in the mesh to interact. These approaches are inspired by several recent proposals in machine learning and coherent photonics to design more error-tolerant and efficient meshes, many of which use single layers of MZIs and nonlocal waveguide interactions [23,26,33,34]; such designs can also be considered to be in the same class of permuting architectures as our proposed permuting rectangular mesh. Adding extra tunable vertical layers, as proposed in Ref. [24], simply adds more tunable paths for the light to achieve a desired output. As shown in Fig. 6, we achieve up to 5 orders of magnitude improvement in convergence at the expense of doubling the mesh size and parameter space.

Like permuting rectangular meshes, multiplane light conversion successfully applies the nonlocal interference idea for efficient spatial mode multiplexing [35,36]. In this protocol, alternating layers of transverse interference profiles and optical Fourier transforms (analogous to what our rectangular permutations accomplish) are applied to reshape input modes of light [35,36]. A similar concept is used in unitary spatial mode manipulation, where stochastic optimization of deformable mirror settings allows for efficient mode conversion [37]. Thus, the idea of efficient unitary learning via a Fourier-inspired permuting approach has precedent in contexts outside of photonic MZI meshes.

An on-chip optimization for multiplane light conversion has been accomplished experimentally in the past using simulated annealing [31]. The success of simulated annealing in experimentally training small unitary photonic devices [31] (rather than gradient descent, as is used in this work) suggests that there are other algorithms aside from gradient descent that may effectively enable on-chip training.

We propose that similar simulated annealing approaches might be made more efficient by sampling Haar phases from uniform distributions and flashing updates onto the device. Similar derivative-free optimizations may also be useful for quantum machine learning [38–40]. Whether such approaches can compete with backpropagation for classical applications remains to be investigated. For experimental on-chip tuning, simulated annealing has the attractive property of only requiring output detectors. For practical machine-learning applications, however, there is currently more literature for backpropagation-based optimization. Furthermore, gradient-based approaches allow for continuous control of phase shifters during the optimization.

Our tensorflow simulations may be useful in the design of optical recurrent neural networks (RNNs) that use unitary operators parameterized by photonic meshes. Such “unitary RNNs” (URNNs) have already been simulated on conventional computers and show some promise in synthetic long-term memory tasks [23,41]. Unitary RNNs are physically implementable using a single mesh with optical nonlinearities and recurrent optoelectronic feedback, suggesting that the architecture discussed in this work is a scalable, energy-efficient option for machine-learning applications. It is possible that some tunable features such as the “bandedness” of unitaries implemented...
by rectangular MZI meshes can be useful (e.g., as an attention mechanism in sequence data) for certain deep-learning tasks that use URNNs.

VII. CONCLUSION

The scalability of gradient-based optimization of Haar random unitary matrices on universal photonic meshes is limited by small reflectivities and MZI phase-shifter sensitivities arising from the constraint of locally interacting components. As shown in Sec. III, the required average reflectivity and sensitivity for each MZI is inversely related to the total number of inputs and outputs affected by the MZI. If the tolerance requirements are not met by the physical components, optimization algorithms will have difficulty converging to a target unitary operator. As shown in Sec. V for the case of in situ backpropagation is generally not achieved if phase shifters are initialized randomly. However, Haar initialization can sufficiently bias the optimization for convergence to a desired random unitary matrix, even in the presence of significant simulated beam-splitter fabrication errors.

In Sec. IV, we propose adding extra tunable beam splitters or mesh nonlocalities to accelerate mesh optimization. Naïve (uniform random) initialization on a standard photonic mesh has difficulty learning random unitary matrices via gradient descent. By introducing nonlocalities in the mesh, we can improve optimization performance without the need for extra parameters. A Haar-initialized redundant architecture can achieve 5 orders of magnitude less mean-square error for a Haar random unitary matrix and decrease optimization time to such a matrix by at least 2 orders of magnitude, as shown in Fig. 7. Our findings suggest that architecture choice and initialization of photonic mesh components may prove important for increasing the scalability and stability of reconfigurable universal photonic devices and their many classical and quantum applications [3,5,6,12,22,38–40,42].

ACKNOWLEDGMENTS

This work is funded by the Air Force Office of Scientific Research, specifically for the Center for Energy Efficient 3D Neuromorphic Nanocomputing (CEN3N2), Grant No. FA9550-181-1-0186. We would like to thank Tyler Hughes, Momchil Minkov, Nate Abebe, Dylan Black, and Ian Williamson for illuminating discussions.

APPENDIX A: SOFTWARE

To reproduce the results of this paper, the reader can be directed to neurophox, an open-source Python package that implements the optimizations and simulations of this paper in numpy and tensorflow. The exact code used to generate the results is provided in the neurophox-notebooks repository.

APPENDIX B: DERIVATION OF BEAM-SPLITTER ERRORS

Unitary matrices generated by lossless MZIs are prone to errors in beam-splitter fabrication. We introduce the error $\epsilon$ to our expression derived in Eq. (1), which is twice the displacement in the beam-splitter split ratio from 50:50. Beam-splitter gates with error $\epsilon$ are defined as $B_r = [\rho + \epsilon \phi \tau$, where $\rho = \sqrt{(1+\epsilon)/2}$ and $\tau = \sqrt{(1-\epsilon)/2}$ are transmissivity and reflectivity amplitudes respectively that result in slight variations from a 50:50 beam splitter. We use this error definition since it is a measurable quantity in the chip; in fact, there are strategies to minimize $\epsilon$ directly [21]. The unitary matrix that we implement in the presence of beam-splitter errors becomes

$$U_{\epsilon} := R_{\phi} B_{\epsilon_2} R_{0} B_{\epsilon_1},$$

$$t_\epsilon := |U_{\epsilon,12}|^2 = |U_{\epsilon,21}|^2,$$

$$r_\epsilon := |U_{\epsilon,11}|^2 = |U_{\epsilon,22}|^2. \quad (B1)$$

If $\epsilon_1 = \epsilon_2 = \epsilon$, which is a reasonable practical assumption for nearby fabricated structures, then solving for $t_\epsilon$ in terms of $t$ gives

$$t_\epsilon = 4|\rho|^2|\tau|^2 t$$

$$= 4t \left(\frac{1}{2} + \epsilon\right) \left(\frac{1}{2} - \epsilon\right) \quad (B2)$$

$$= t(1 - \epsilon^2).$$

Similarly, we can solve for $r_\epsilon$:

$$r_\epsilon = 1 - t_\epsilon = r + t \cdot \epsilon^2. \quad (B3)$$

As we have discussed in this paper (and as we later show in Fig. 12), photonic errors $\epsilon$ (standard deviation of 0.1) can affect the optimized phase shifts for unitary matrices. The above constraints on $r_\epsilon$ and $t_\epsilon$ suggest that limited transmissivity is likely in the presence of fabrication errors, which can inhibit progressive setup of unitary meshes [21,24]. However, we later show through tensorflow simulation that in situ backpropagation updates can to some extent address this issue using a more sophisticated experimental protocol involving phase conjugation and interferometric measurements [7].

APPENDIX C: HAAR MEASURE

In this section, we outline a proof for the Haar measure of a unitary matrix in terms of the physical parameters of a photonic mesh to supplement our discussion of Haar phase and the proof in Ref. [16]. The Haar measure for $U(N)$ can be defined in two physical basis representations: the measurement basis represents measurements after each MZI.
and the transmissivity basis represents the transmissivity of each MZI.

To make our explanation simpler, we adopt the orthogonalization protocol used in Ref. [11]. In this representation, we define the triangular mesh $U_T$ as

$$U_T = \prod_{m=0}^{N-1} U^{(N-m)}_m,$$

$$U^{(m)} = \prod_{n=1}^{m-1} U_{N-n} \left( \theta_n^{(m)}, \phi_n^{(m)} \right) \cdot D_m(y_{N-m+1}),$$

where $D_m$ is a diagonal matrix representing a single-mode phase shift at index $N - m + 1$.

The $N$ operators $U^{(m)}$ represent the diagonal layers of the triangular mesh and their role is to project inputs from Hilbert space dimension $m$ to $m - 1$ recursively until we reach a single-mode phase shift in $U^{(1)} = D_1(y_N)$. Our proof moves the same direction as Reck’s orthogonalization procedure; we iteratively solve for $U^{(m)}$ in decreasing order from $m = N$ to $m = 1$. For each layer $m$, there are $2m - 1$ complex hyperspherical coordinates ($m - 1$ “amplitude” coordinates and $m$ “phase” coordinates). The first column vector of $U$ can be recovered by shining light (using a unit power) through the top port of the layer (given by $n = N - m + 1$) and measuring the output fields in the triangular mesh generated by $U^{(m)}$, as shown in Fig. 8(b). As mentioned in Refs. [11] and [22], progressive optimization moves in the opposite direction; the desired output fields are shined back into the device and the transmissivities $t_n^{(m)}$ and phases $\phi_n^{(m)}$ for each layer $m$ (moving from $N$ to 1) can be progressively tuned until all the power lies in the top input port for that layer.

The measurement basis is an unbiased Haar measure (as shown in Ref. [16] using Gaussian random vectors) and can be physically represented by the power $x_n$ measured at waveguides $n \leq m - 1$ due to shining light through the top input port for that layer. Unlike the proof in Ref. [16], we choose our constraint such that the input power $P = 1$ rather than $P \in \mathbb{R}^+$, which introduces a normalization prefactor in our Haar measure by integration over all possible $P$. [This prefactor is exactly $\int_0^\infty dP e^{-P} P^{m-1}$.] This allows us to ignore the power in the final output port $x_N$ because energy conservation ensures that we have the constraint $x_N = 1 - \sum_{n=1}^{N-1} x_n$. Therefore, our simplified Cartesian basis for each $m$ (ignoring the normalization prefactor)

$$d\mu(U^{(m)}) \propto d\gamma_{N-m} \prod_{n=1}^{m-1} dx_n \prod_{n=1}^m d\phi_n.$$  

(C2)

Now we represent the Cartesian power quantities $x_n$ explicitly in terms of the component transmissivities, which we have defined already to be $t_n = \cos^2(\theta_n/2)$. Using the same convention as hyperspherical coordinates, we get the following recursive relation for $x_n$, as shown diagrammatically by following the path of light from the top input port in Fig. 8(b):

$$x_n = (1 - t_n) \prod_{k=1}^{N-1} t_k.$$  

(C3)

Intuitively, Eq. (C3) implies that the power $x_n$ measured at port $n$ is given by light that is transmitted by the first $n - 1$ components along the path of light and then reflected by the $n$th component. In other words, $x_n$ follows a geometric distribution.

We can use Eq. (C3) to find the Jacobian $J \in \mathbb{R}^{N-1 \times N-1}$ relating the $x_n$ and the $t_k$. We find that we have a lower triangular matrix $J$ with diagonal elements for $n \leq N - 1$:

$$J_{nn} = -\prod_{k=1}^{N-1} t_k.$$  

(C4)

We know $J$ is lower triangular since for all $n' > n$, $J_{nn'} = \partial x_n / \partial t_{n'} = 0$ from Eq. (C3).

Since the determinant of a lower triangular matrix is the same as the product of the diagonal, we can directly evaluate the unbiased measure (off by a normalization factor).
constant) as

\[ d\mu(U^{(m)}) \propto d\gamma_{N-m+1} \det J \prod_{n=1}^{m-1} dt_n \prod_{n=1}^{m} d\phi_n \]

\[ = d\gamma_{N-m+1} \prod_{n=1}^{m-1} J_{mn} \prod_{n=1}^{m} dt_n \prod_{n=1}^{m} d\phi_n \]

\[ \propto d\gamma_{N-m+1} \prod_{n=2}^{m} r_{n-m} \prod_{n=1}^{m} dt_n \prod_{n=1}^{m} d\phi_n. \quad (C5) \]

To get the total Haar measure, we multiply the volume elements for the orthogonal components \( d\mu(U^{(m)}) \). We get from this procedure that the sensitivity index \( \alpha_{nt} = N - n \) for a triangular mesh in Eq. (C5) (independent of \( \ell \)), which can be seen using Fig. 8. We can express this Haar measure in terms of \( \alpha_{nt} = N - n \), the probability distribution for the transmissivity, and \( P_{\alpha_{nt}}(\theta_{nt}/2) \), the probability distribution for the phase shift corresponding to that same transmissivity, assuming appropriate choice \( n, \ell \) for the triangular mesh:

\[ d\mu(U) = \prod_{n=1}^{N} d\mu(U^{(n)}) \]

\[ = \prod_{n} d\gamma_{n} \prod_{n,\ell} Q_{\alpha_{nt}}(t_{nt}) dt_{nt} d\phi_{nt} \quad (C6) \]

\[ = \prod_{n} d\gamma_{n} \prod_{n,\ell} P_{\alpha_{nt}}(\theta_{nt}/2) d\theta_{nt} d\phi_{nt}. \]

We can now normalize Eq. (C5) using the normalization factor for \( P \) to get \( Q_{\alpha_{nt}}(t_{nt}) \) and then substitute \( t_{nt} = \cos^2(\theta_{nt}/2) \) to get our desired expression for \( P_{\alpha_{nt}}(\theta_{nt}/2) \):

\[ Q_{\alpha_{nt}}(t_{nt}) = \alpha_{nt} t_{nt}^{2\alpha_{nt}-1} \]

\[ P_{\alpha_{nt}}(\theta_{nt}/2) = \alpha_{nt} \sin^2(\theta_{nt}/2) \left[ \cos^2(\theta_{nt}/2) \right]^{2\alpha_{nt}-1}. \quad (C7) \]

Finally, we can recover the Haar phase parameter \( \xi_{nt} \in [0, 1] \) (i.e., the cumulative density function) in terms of either \( t_{nt} \) or \( \theta_{nt} \):

\[ \xi_{nt} = \left[ \cos^2(\theta_{nt}/2) \right]^{2\alpha_{nt}} = t_{nt}^{\alpha_{nt}}. \quad (C8) \]

Finally, as explained in Ref. [16], we can use the Clements decomposition [10] to find another labeling for \( \alpha_{nt} \) in a rectangular mesh that gives probability distributions and Haar phases in the same form as Eqs. (C7) and (C8) respectively.

**APPENDIX D: UNITARY BANDSIZES**

We would like to quantify the bandedness of matrices implemented by the meshes with randomly initialized phases. We define the \( \eta \) bandsize as the minimum number of matrix elements whose absolute value squared sums to \((1 - \eta)N\). Note that our \( \eta \)-bandsize measurement is agnostic of the ordering of the inputs and outputs and is therefore agnostic to any permutations that may be applied at the end of the decomposition. In photonics terms, if \( \eta = 0.001 \), let \( r_i \) measure the fraction of output waveguides over which 99.9\% of the power is distributed when light is input into waveguide \( i \). The \( \eta \) bandsize is \( r_i \) averaged over all \( i \). Sampling from our matrix distributions, we observe the relationship between the bandsize (given \( \eta = 0.001 \)) and the dimension \( N \) in Fig. 9.

**APPENDIX E: INTRODUCING PHOTONIC ERRORS IN A REDUNDANT MESH**

When photonic errors are added to the redundant mesh, specifically the 256-layer mesh, we observe a slight decrease in optimization performance in Fig. 10, similar to what we observed for the rectangular and permuting rectangular meshes in Fig. 7. This decrease in performance, however, is less concerning considering that we still achieve a mean-square error of around \( 10^{-5} \), suggesting that RRM might be more robust to photonic errors even during on-chip optimization.

**APPENDIX F: PHOTONIC SINGULAR VALUE DECOMPOSITION SIMULATIONS**

We compare the simulated performance of such rectangular and permuting rectangular architectures in the SVD configuration discussed in Refs. [22] and [6]. Such architectures would allow one to perform arbitrary linear...
operations with a relatively small footprint and may have some other useful dimensionality-reduction properties in machine-learning contexts.

In SVD, we represent complex matrix \( \hat{A} \in \mathbb{C}^M \times \mathbb{C}^N \) as 
\[ \hat{A} = \hat{U} \hat{\Sigma} \hat{V}^\dagger, \]
where \( \hat{\Sigma} \) is a diagonal matrix implemented on-chip, with \( \min(M, N) \) single-mode gain or attenuating elements, and \( \hat{U}, \hat{V}^\dagger \) are unitary matrices implemented in a photonic mesh. While \( \hat{A} \) has \( 2MN \) free parameters, any global optimization for a photonic SVD implementation using rectangular meshes can have at most \( D = N(N - 1) + M(M - 1) + 2\min(N, M) \geq 2MN \) free parameters, with equality when \( M = N \). In the triangular architecture discussed in Ref. [22], the total complexity of parameters can be exactly \( D = 2MN \) when setting a subset of the beam splitters to a bar state. In the case where the total number of singular values for \( \hat{A} \) is \( S < \min(M, N) \), we get \( D = 2S(M + N - S) \) tunable elements. Additionally, there is an "effective redundancy" in that some vectors in \( U, V \) are more important than others due to the singular values.

In our simulations, we investigate a SVD architecture for 
\[ A = U \Sigma V^\dagger \]
composed of the unitaries \( U \in \mathbb{C}^M \times \mathbb{C}^M \) and \( V \in \mathbb{C}^N \times \mathbb{C}^N \). Note that such an architecture is redundant when \( M \neq N \), so we focus on the simple case of \( M = N = 64 \).

We define our train and test cost functions analogous to the unitary mean-square error cost functions as
\[ L_{\text{test}} = \frac{\| \hat{A} - A \|_F^2}{2\| A \|_F^2}, \]
\[ L_{\text{train}} = \frac{\| \hat{A} X - AX \|_F^2}{2\| A \|_F^2}, \]
where \( \hat{A} = \hat{U} \hat{\Sigma} \hat{V}^\dagger \) is defined in Sec. V.

We randomly generate \( A \in \mathbb{C}^N \times \mathbb{C}^M \) by expressing 
\[ A_{ij} = a + ib, \]
where \( a, b \sim N(0, 1) \). The synthetic training batches of unit-norm complex vectors are represented by 
\[ X \in \mathbb{C}^{N \times 2N}. \]

Assuming a procedure similar to Ref. [7] can be used in presence of gains and optimization, the permuting rectangular mesh converges slightly faster but is significantly more resilient to uniform random phase initialization compared to the rectangular mesh as shown in Fig. 11. Both optimizations are minimally affected by beam-splitter error, unlike what is seen in the unitary optimization case.

**APPENDIX G: PERIODIC PARAMETERS**

We comment on our reported values of \( \theta_{nt} \) in the checkerboard plots in Figs. 3, 6 (of the main text), and 12. Since our simulated optimization does not have the explicit constraint that \( \theta_{nt} \in [0, \pi] \), we report the “absolute \( \theta_{nt} \)” that obeys this constraint. This corresponds to the following transformation (assuming \( \theta_{nt} \) is originally between \( 0 \) and \( 2\pi \)):
\[ \theta_{nt} \rightarrow \begin{cases} \theta_{nt} & \theta_{nt} \leq \pi \\ 2\pi - \theta_{nt} & \theta_{nt} > \pi \end{cases}. \]

Note that a treatment similar to that in Eq. (G1) can be used to represent the Haar phase \( \xi \in [0, 1] \) in terms of a “periodic” Haar phase \( \tilde{\xi} \in [0, 2] \) with period 2:
\[ \xi(\tilde{\xi}) = \begin{cases} \tilde{\xi} & \tilde{\xi} \leq 1 \\ 2 - \tilde{\xi} & \tilde{\xi} > 1 \end{cases}. \]

Note that both \( \tilde{\xi} \) and \( \theta_{nt} \) can therefore be made to vary continuously from \( (-\infty, \infty) \) with \( \tilde{\xi} \) having a period of 2 and \( \theta_{nt} \) having a period of \( 2\pi \). We map these periodic parameters to their half-periods according to Eqs. (G1) and (G2) based on symmetry arguments.
FIG. 12. Comparison of learned matrix errors and learned $\theta_{nd}$ weights after 20,000 iterations for the Adam update at learning rate 0.0025 and batch size 256 for the simple unitary network. We consider two meshes: (1) rectangular mesh (RM) and (2) permuting rectangular mesh (PRM). We consider three conditions for each mesh: (1) ideal (with Haar random unitary initialization); (2) photonic beam-splitter error displacement $\epsilon \sim \mathcal{N}(0,0.01)$; (3) random initialization.
APPENDIX H: TRAINING SIMULATION COMPARISONS

In Fig. 12, we compare the performance for our unitary network experiment over our aforementioned conditions in Sec. V. For each plot, we also have an associated video, showing how the parameter distributions, estimates, and errors vary during the course of the optimization, available online.

There are several takeaways from these plots. First, the reflectivities of the MZIs near the center of the mesh are much smaller in the optimized rectangular meshes than in the permuting rectangular meshes, which correspondingly results in a smaller variance $\theta_{n\ell}$ for the rectangular mesh as shown explicitly in Fig. 13. Second, the gradient descent algorithm has a hard time finding the regime of Haar random matrices after a uniform random phase initialization. The values of $\theta_{n\ell}$ are much larger than they need to be even 100 iterations into the optimization. This is likely evidence of a “vanishing gradient” problem when the mesh is not Haar initialized. Finally, an important observation for the meshes with beam-splitter error is that the $\theta_{n\ell}/2$ distribution shifts slightly toward 0 in the rectangular mesh. This is a consequence of the limits in reflectivity and transmissivity in each MZI due to a beam-splitter fabrication error as discussed in Sec. II.

Our simulated permuting rectangular implementation uses the same layer definitions as defined in Eq. (11), except the $P_k$’s with the most layers are in the center of the mesh and the $P_k$’s with the fewest layers are near the inputs and outputs of the mesh. In Fig. 4, $P_2$ and $P_3$ would be switched, and for $N = 128$, the order is $[P_2, P_4, P_6, P_5, P_3, P_1]$. We find this configuration to perform best for gradient-based optimization, although the architecture in Eq. (11) gives improvements over the rectangular mesh as well.

APPENDIX I: AN EQUIVALENT DEFINITION FOR $\alpha_{n\ell}$

Let $\alpha_{n\ell}$ be the sensitivity index for a MZI (“node”) at (waveguide, layer) coordinates $(n, \ell)$ in a local decomposition for an $N \times N$ unitary operator. We define the “row coordinate” or waveguide index $n$ from the MZI’s operator $U_n$ coupling waveguides $n$ and $n+1$, and we define the “column coordinate” or layer index $\ell = k + 1$, where $k$ is the maximum number of operators applied to a reachable input. (This is equivalent to the vertical layers definition in Fig. 1.) The reachable inputs $I_{n\ell}$ are the subset of input modes affecting the immediate inputs of the MZI at $(n, \ell)$, and the reachable outputs $O_{n\ell}$ are the subset of output modes affected by the immediate outputs of the MZI.

Following the definitions in Ref. [16], in the triangular scheme, $\alpha_{n\ell} := N - n$, and in the rectangular scheme,
TABLE I. Induction on x and y within each of the quadrants in the mesh.

| Quadrant | Induction | d(x) = ⋯ | s_y[y] = ⋯ | |xy| = ⋯ | |O_{xy}| = ⋯ |
|----------|-----------|-----------|-----------|-----------|-----------|-----------|-----------|
| \(x' \leq \frac{N}{2}, y' \leq \frac{N}{2}\) | \(x = x' - 1\) | \(d(n, \ell) - 2\) | \(s_y[y']\) | \(|I_{xy}| - 2\) | \(|O_{xy}|\) |
| \(x' \leq \frac{N}{2}, y' > \frac{N}{2}\) | \(y = y' - 1\) | \(d(n, \ell)\) | \(s_y[y'] + 2\) | \(|I_{xy}| - 2\) | \(|O_{xy}|\) |
| \(x' > \frac{N}{2}, y' \leq \frac{N}{2}\) | \(x = x' + 1\) | \(d(n, \ell) - 2\) | \(s_y[y']\) | \(|I_{xy}|\) | \(|O_{xy}| - 2\) |
| \(x' > \frac{N}{2}, y' > \frac{N}{2}\) | \(y = y' + 1\) | \(d(n, \ell)\) | \(s_y[y'] + 2\) | \(|I_{xy}| - 2\) | \(|O_{xy}|\) |

Proof: In the rectangular mesh, \(\alpha_{nt} := d(n, \ell) + 1 - s_{nt}[\ell]\), where \(d(n, \ell)\) is the number of nodes on the diagonal (measured along paths of constant \(n + \ell\)) containing a rotation parameterized by \(\theta_{nt}\), and \(s_{nt}\) is a sequence of decreasing odd integers \(d(n, \ell) \geq k_{odd} \geq 1\), followed by increasing even integers \(2 \leq k_{even} \leq d(n, \ell)\), as defined in Ref. [16]. We prove below that for both the triangular and rectangular meshes, \(\alpha_{nt} = |I_{nt}| + |O_{nt}| - N - 1\).

Lemma 1: In the triangular mesh, \(\alpha_{nt} = |I_{nt}| + |O_{nt}| - N - 1\).

Proof: In the triangular mesh (shown for \(N = 8\) in Fig. 8), \(\alpha_{nt} := N - n\), so we wish to show that \(N - n = |I_{nt}| + |O_{nt}| - N - 1\) or

\[
2N + 1 = |I_{nt}| + |O_{nt}| + n. \tag{11}
\]

Suppose Eq. (11) holds for some arbitrary \(n', \ell'\) in the mesh, such that \(2N + 1 = |I_{nt}| + |O_{nt}| + n'\). First, induct on \(n\): if we take \(n = n' + 2\) and \(\ell = \ell'\), then \(|I_{nt}| = |I_{nt'}| - 1\) and \(|O_{nt}| = |O_{nt'}| - 1\). Next, induct on \(\ell\): if we take \(n = n'\) and \(\ell = \ell' + 2\), then \(|I_{nt}| = |I_{nt'}| + 1\) and \(|O_{nt}| = |O_{nt'}| - 1\). In both cases, Eq. (11) holds.

Traversals by 2 along \(n\) or \(\ell\) from a starting node can reach all nodes with the same parity of \(n\), so we need no base cases. Consider the apex node at \(n = 1, \ell = N - 1\). Suppose there is a rotation at \(n = 2, \ell = 2, \ell = N\). The former has \(|I_{nt}| = |O_{nt}| = N\) and the latter has \(|I_{nt}| = N\) and \(|O_{nt}| = N - 1\). In both cases, Eq. (11) is satisfied, so the lemma holds by induction.

Lemma 2: In the rectangular mesh, \(\alpha_{nt} = |I_{nt}| + |O_{nt}| - N - 1\).

TABLE II. Induction on x or y across each of the borders of \(x, y = [N/2]\).

| \(x'\) | \(y'\) | Induction | \(d(x) = \cdots\) | \(s_x[y] = \cdots\) | \(|I_{xy}| = \cdots\) | \(|O_{xy}| = \cdots\) |
|-------|-------|-----------|-----------|-----------|-----------|-----------|
| \([N/2]\) | Any | \(x = x' + 1\) | \(d(n, \ell) - 1\) | \(s_x[y']\) | \(|I_{xy}| + 0[1]\) | \(|O_{xy}| - 1[0]\) |
| Any | \([N/2]\) | \(y = y' + 1\) | \(d(n, \ell)\) | \(s_x[y'] + 1\) | \(|I_{xy}|\) | \(|O_{xy}| - 1\) |
There are two boundaries at \( x, y = [N/2] \) which separate four quadrants that must be considered, depicted by gray lines in Fig. 14. We will induct on \( d(x') \) and \( 1 + s_x y' \) for \( x' y' \) in the mesh, such that \( d(x') + 1 - s_x y' = |I_{x'y'}| + |O_{x'y'}| - N - 1 \). First, we induct on \( x \) and \( y \) within each quadrant; the results are tabulated in Table I. In every case, \( d(x) - s_x y' - |I_{x'y'}| - |O_{x'y'}| = (n, \ell) - s_x y' - |I_{x'y'}| - |O_{x'y'}| \), so Eq. (14) remains satisfied.

Next, we induct across the \( x, y = [N/2] \) boundaries, shown in Table II. Again, in every case, \( d(x') - s_x y' - |I_{x'y'}| - O_{x'y'}| = (n, \ell) - s' x y - |I_{x'y'}| - |O_{x'y'}| \), satisfying Eq. (14).

Finally, note that the base case of the top left MZI at \((n, \ell) = (1, 1), (x, y) = (1, [N/2])\) holds, with \( d(x) + 1 - s_x y' = 1 = 2 + N - N - 1 = |I_{n\ell}| + |O_{n\ell}| - N - 1 \). This completes the proof in the \((x, y)\) basis, and since there is a one-to-one mapping between \((x, y) \leftrightarrow (n, \ell)\), the condition holds for induction.


